



YOUSHANG SEMICONDUCTOR

**设计研发新型功率器件**

**各类小信号开关**

**中低压及高压大电流等场效应管**

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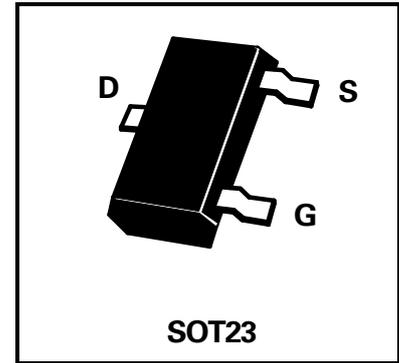
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**FEATURES**

- \* 60 Volt  $V_{DS}$
- \*  $R_{DS(on)}=14\Omega$

PARTMARKING DETAIL – ML

COMPLEMENTARY TYPE – NK-ZVN3306F



**ABSOLUTE MAXIMUM RATINGS.**

PARAMETER	SYMBOL	VALUE	UNIT
Drain-Source Voltage	$V_{DS}$	-60	V
Continuous Drain Current at $T_{amb}=25^{\circ}C$	$I_D$	-90	mA
Pulsed Drain Current	$I_{DM}$	-1.6	A
Gate Source Voltage	$V_{GS}$	$\pm 20$	V
Power Dissipation at $T_{amb}=25^{\circ}C$	$P_{tot}$	330	mW
Operating and Storage Temperature Range	$T_j:T_{stg}$	-55 to +150	$^{\circ}C$

**ELECTRICAL CHARACTERISTICS (at  $T_{amb} = 25^{\circ}C$  unless otherwise stated)**

PARAMETER	SYMBOL	MIN.	MAX.	UNIT	CONDITIONS.
Drain-Source Breakdown Voltage	$BV_{DSS}$	-60		V	$I_D=-1mA, V_{GS}=0V$
Gate-Source Threshold Voltage	$V_{GS(th)}$	-1.5	-3.5	V	$I_D=-1mA, V_{DS}=V_{GS}$
Gate-Body Leakage	$I_{GSS}$		20	nA	$V_{GS}=\pm 20V, V_{DS}=0V$
Zero Gate Voltage Drain Current	$I_{DSS}$		-0.5 -50	$\mu A$ $\mu A$	$V_{DS}=-60V, V_{GS}=0V$ $V_{DS}=-48V, V_{GS}=0V, T=125^{\circ}C(2)$
On-State Drain Current(1)	$I_{D(on)}$	-400		mA	$V_{DS}=-18V, V_{GS}=-10V$
Static Drain-Source On-State Resistance (1)	$R_{DS(on)}$		14	$\Omega$	$V_{GS}=-10V, I_D=-200mA$
Forward Transconductance (1)(2)	$g_{fs}$	60		mS	$V_{DS}=-18V, I_D=-200mA$
Input Capacitance (2)	$C_{iss}$		50	pF	$V_{DS}=-18V, V_{GS}=0V, f=1MHz$
Common Source Output Capacitance (2)	$C_{oss}$		25	pF	
Reverse Transfer Capacitance (2)	$C_{rss}$		8	pF	
Turn-On Delay Time (2)(3)	$t_{d(on)}$		8	ns	$V_{DD}\approx -18V, I_D=-200mA$
Rise Time (2)(3)	$t_r$		8	ns	
Turn-Off Delay Time (2)(3)	$t_{d(off)}$		8	ns	
Fall Time (2)(3)	$t_f$		8	ns	

(1) Measured under pulsed conditions. Width=300 $\mu s$ . Duty cycle  $\leq 2\%$  (2) Sample test.

(3) Switching times measured with 50 $\Omega$  source impedance and <5ns rise time on a pulse generator  
Spice parameter data is available upon request for this device

## TYPICAL CHARACTERISTICS

